

TPS61099x 静态电流极低的同步升压转换器

1 特性

- 600 nA 超低 I_Q 流入 V_{OUT} 引脚
- 400 nA 超低 I_Q 流入 V_{IN} 引脚
- 工作输入电压范围为 0.7V 至 5.5V
- 可调节输出电压范围为 1.8V 至 5.5V
- 提供固定输出电压版本
- 最小开关峰值电流限值为 0.8A
- 降压模式下的稳压输出电压
- 关断期间真正实现断开
- 使用固定输出电压版本时，10 μ A 负载条件下的效率高达 75%
- 在 10mA 至 300mA 负载条件下，效率高达 93%
- 6 焊球 1.23 mm x 0.88 mm 晶圆级芯片封装 (WCSP) 封装

2 应用

- 存储器液晶显示屏 (LCD) 偏置
- 光学心率监测发光二极管 (LED) 偏置
- 可穿戴设备
- 低功耗无线应用
- 便携式产品
- 电池供电系统

3 说明

TPS61099x 是一款超低静态电流为 1 μ A 的同步升压转换器。该器件设计用于由碱性电池、NiMH 充电电池、Li-Mn 电池或锂离子充电电池供电的产品，其在轻载条件下的高效运行对于延长电池使用寿命至关重要。

TPS61099x 升压转换器采用迟滞控制拓扑，可在静态电流最低的情况下实现最高效率。该器件在轻载条件下仅消耗 1 μ A 静态电流；当负载为 10 μ A 时，使用固定输出电压版本可实现高达 75% 的效率。该器件在 3.3V 至 5V 转换过程中的输出电流高达 300mA，在 200mA 负载条件下可实现高达 93% 的效率。

TPS61099x 还可为不同应用提供降压模式和直通模式。在降压模式下，即使输入电压高于输出电压，输出电压仍可调节为目标值。在直通模式下，输出电压随着输入电压发生变化。当 $V_{IN} > V_{OUT} + 0.3V$ 时，TPS61099x 退出降压模式并转入直通模式。

TPS61099x 在禁用状态下能够将负载与输入电源断开，真正实现关断，从而降低电流消耗。

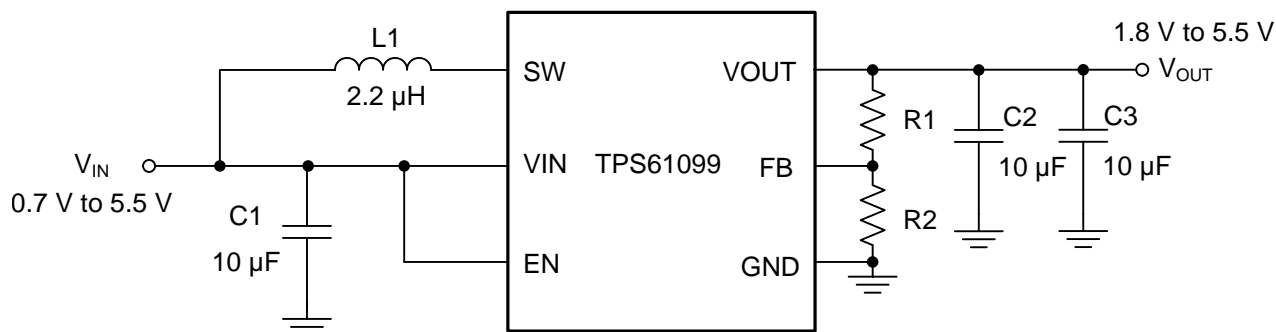
TPS61099x 具有可调节输出电压版本和固定输出电压版本。该器件采用 6 焊球 1.23mm x 0.88mm WCSP 封装。

器件信息⁽¹⁾

器件型号	封装	封装尺寸 (标称值)
TPS61099	WCSP (6)	1.23mm x 0.88mm
TPS61099x	WCSP (6)	1.23mm x 0.88mm

(1) 要了解所有可用封装，请参见本文档末尾的可订购产品附录。

典型应用电路



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4 修订历史记录

Changes from Original (June 2016) to Revision A

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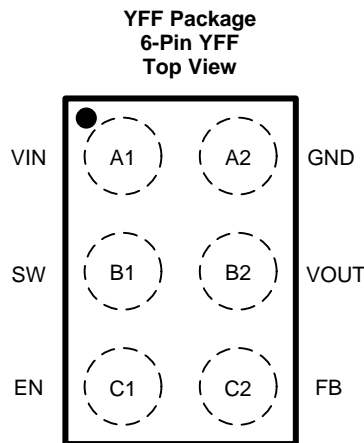
• 已添加 完整数据表 - 全局	1
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5 Device Comparison Table

PART NUMBER	OUTPUT VOLTAGE
TPS61099	Adjustable
TPS610997 ⁽¹⁾	5.0 V

(1) Product Preview. Contact TI factory for more information.

6 Pin Configuration and Functions



Pin Functions

PIN		TYPE	DESCRIPTION
NO.	NAME		
A1	VIN	I	IC power supply input
B1	SW	PWR	Switch pin of the converter. It is connected to the inductor
C1	EN	I	Enable logic input. Logic high voltage enables the device; logic low voltage disables the device. Do not leave it floating.
A2	GND	PWR	Ground
B2	VOUT	PWR	Boost converter output
C2	FB	I	Voltage feedback of adjustable output voltage. Connect to the center tap of a resistor divider to program the output voltage. Connect to VOUT pin for fixed output voltage versions.

7 Specifications

7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

		MIN	MAX	UNIT
Voltage range at terminals ⁽²⁾	VIN, SW, VOUT, FB, EN	-0.3	6.0	V
Operating junction temperature, T _J		-40	150	°C
Storage temperature range, T _{stg}		-65	150	°C

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values are with respect to network ground terminal.

7.2 ESD Ratings

		VALUE	UNIT
V _(ESD) Electrostatic discharge	Human Body Model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins ⁽¹⁾	±2000	V
	Charged Device Model (CDM), per JEDEC specification JESD22-C101, all pins ⁽²⁾	±500	

- (1) JEDEC document JEP155 states that 500V HBM rating allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250V CDM rating allows safe manufacturing with a standard ESD control process.

7.3 Recommended Operating Conditions

		MIN	NOM	MAX	UNIT
V _{IN}	Input voltage range	0.7		5.5	V
V _{OUT}	Output voltage range	1.8		5.5	V
L	Inductor	0.7	2.2	2.86	μH
C _{IN}	Input capacitor	1.0	10		μF
C _{OUT}	Output capacitor	10	20	100	μF
T _J	Operating virtual junction temperature	-40		125	°C

7.4 Thermal Information

THERMAL METRIC ⁽¹⁾		TPS61099	UNIT
		YFF (6 BALLS, WCSP)	
R _{θJA}	Junction-to-ambient thermal resistance	134.4	°C/W
R _{θJctop}	Junction-to-case (top) thermal resistance	0.9	°C/W
R _{θJB}	Junction-to-board thermal resistance	36.1	°C/W
ψ _{JT}	Junction-to-top characterization parameter	0.1	°C/W
ψ _{JB}	Junction-to-board characterization parameter	36.2	°C/W
R _{θJCbot}	Junction-to-case (bottom) thermal resistance	N/A	°C/W

- (1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, [SPRA953](#).

7.5 Electrical Characteristics

$T_J = -40^{\circ}\text{C}$ to 125°C and $V_{IN} = 0.7\text{ V}$ to 5.5 V . Typical values are at $V_{IN} = 3.7\text{ V}$, $T_J = 25^{\circ}\text{C}$, unless otherwise noted.

PARAMETER		Version	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Power Supply							
V_{IN}	Input voltage range	TPS61099x		0.7		5.5	V
V_{UVLO}	Input under voltage lockout threshold	TPS61099x	V_{IN} rising		0.6	0.7	V
	UVLO hysteresis	TPS61099x			200		mV
I_Q	Quiescent current into VIN pin	TPS61099x	IC enabled, no Load, no Switching $T_J = -40^{\circ}\text{C}$ to 85°C		0.4	1.1	μA
	Quiescent current into VOUT pin	TPS61099x	IC enabled, no Load, no Switching, Boost or Down Mode $T_J = -40^{\circ}\text{C}$ to 85°C		0.6	1.5	μA
I_{SD}	Shutdown current into VIN pin	TPS61099x	IC disabled, $V_{IN} = 3.7\text{ V}$, $V_{OUT} = 0\text{ V}$ $T_J = -40^{\circ}\text{C}$ to 85°C		0.5	1.6	μA
Output							
V_{OUT}	Output voltage range	TPS61099x		1.8		5.5	V
V_{REF}	Feedback reference voltage	TPS61099	$V_{IN} < V_{OUT}$, PWM mode	0.98	1.00	1.02	V
		TPS61099	$V_{IN} < V_{OUT}$, PFM mode		1.03		V
V_{OVP}	Output overvoltage protection threshold	TPS61099x	V_{OUT} rising	5.6	5.8	6.0	V
	OVP hysteresis	TPS61099x			100	200	mV
I_{FB_LKG}	Leakage current into FB pin	TPS61099x	$V_{FB} = 1.0\text{ V}$		10	50	nA
Power Switch							
$R_{DS(on)_LS}$	Low side switch on resistance	TPS61099x	$V_{OUT} = 5.0\text{ V}$		250		m Ω
			$V_{OUT} = 3.3\text{ V}$		300		m Ω
			$V_{OUT} = 1.8\text{ V}$		400		m Ω
$R_{DS(on)_HS}$	Rectifier on resistance	TPS61099x	$V_{OUT} = 5.0\text{ V}$		300	350	m Ω
			$V_{OUT} = 3.3\text{ V}$		350	450	m Ω
			$V_{OUT} = 1.8\text{ V}$		500	750	m Ω
I_{LH}	Inductor current ripple	TPS61099x	$V_{OUT} = 5.0\text{ V}$		350		mA
			$V_{OUT} = 3.3\text{ V}$		300		mA
			$V_{OUT} = 1.8\text{ V}$		250		mA
I_{LIM}	Current limit threshold	TPS61099x	$V_{OUT} \geq 2.5\text{ V}$, boost operation	0.8	1	1.25	A
			$V_{OUT} < 2.5\text{ V}$, boost operation	0.5	0.75		A
I_{SW_LKG}	Leakage current into SW pin (from SW pin to GND)	TPS61099x	$V_{SW} = 5.0\text{ V}$, no switch, $T_J = -40^{\circ}\text{C}$ to 85°C			200	nA
Control Logic							
V_{IL}	EN input low voltage threshold	TPS61099x	$V_{IN} \leq 1.5\text{ V}$	0.2 x V_{IN}			V
V_{IH}	EN input high voltage threshold	TPS61099x	$V_{IN} \leq 1.5\text{ V}$			0.8 x V_{IN}	V
V_{IL}	EN input low voltage threshold	TPS61099x	$V_{IN} > 1.5\text{ V}$	0.4			V
V_{IH}	EN input high voltage threshold	TPS61099x	$V_{IN} > 1.5\text{ V}$			1.2	V
I_{EN_LKG}	Leakage current into EN pin	TPS61099x	$V_{EN} = 5.0\text{ V}$			50	nA
	Overtemperature protection	TPS61099x			150		$^{\circ}\text{C}$
	Overtemperature hysteresis	TPS61099x			25		$^{\circ}\text{C}$

7.6 Typical Characteristics

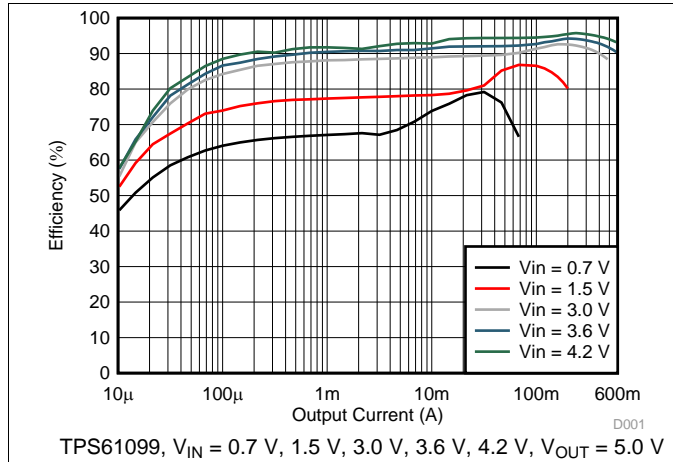


图 1. Load Efficiency with Different Inputs

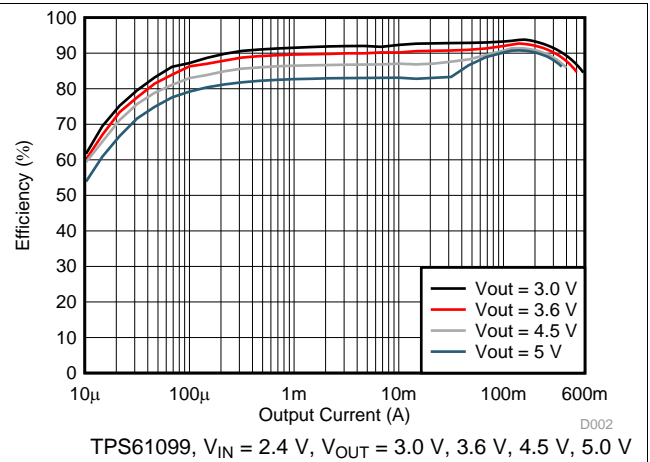


图 2. Load Efficiency with Different Outputs

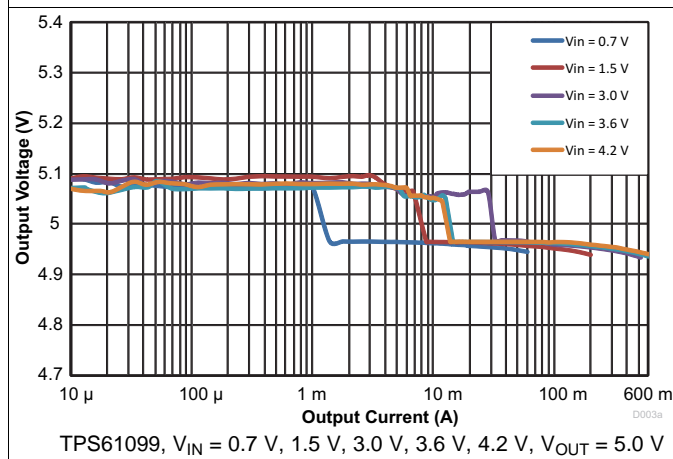


图 3. Load Regulation

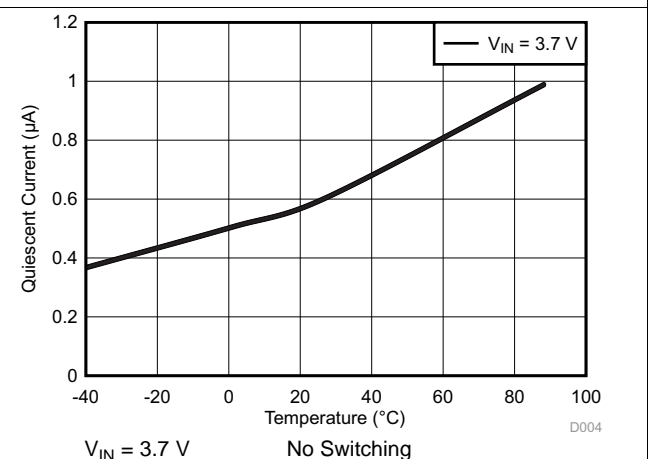


图 4. Quiescent Current into V_{OUT} vs Temperature

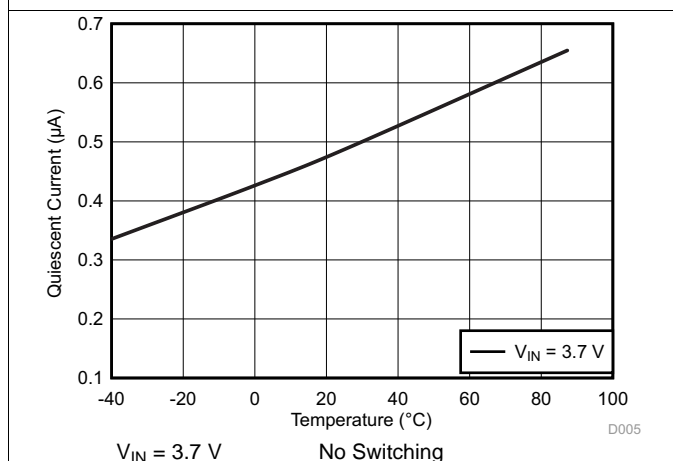


图 5. Quiescent Current into V_{IN} vs Temperature

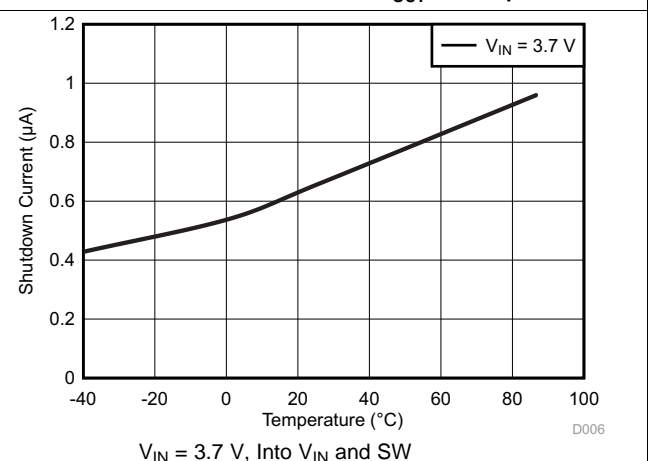
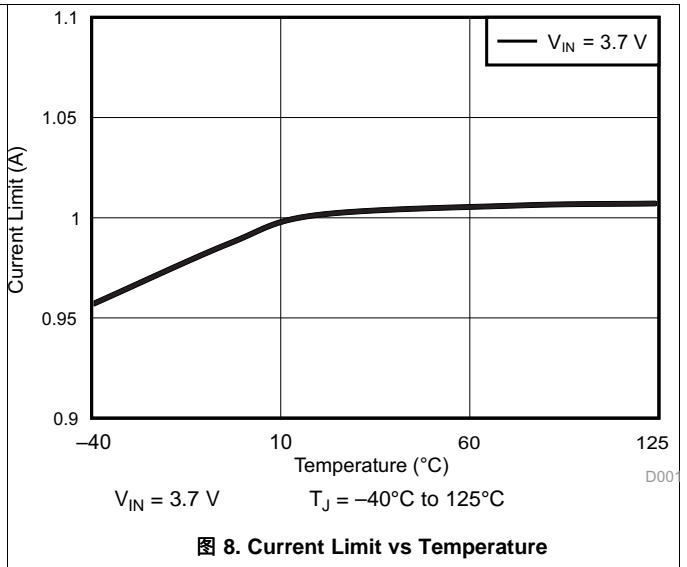
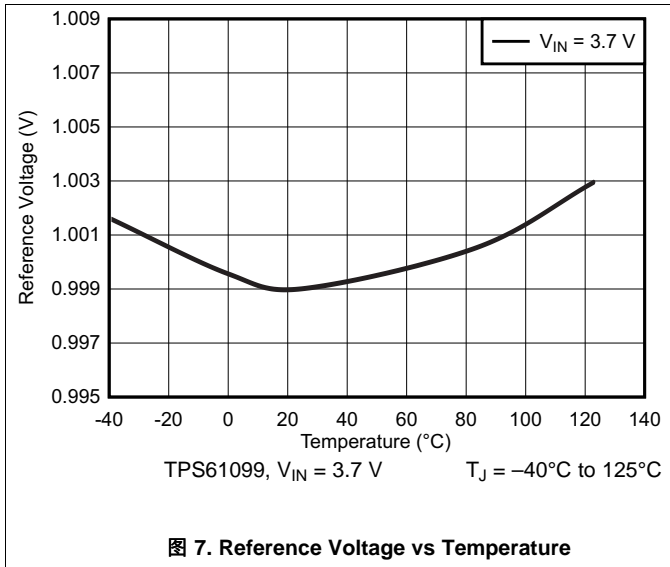


图 6. Shutdown Current vs Temperature

Typical Characteristics (接下页)



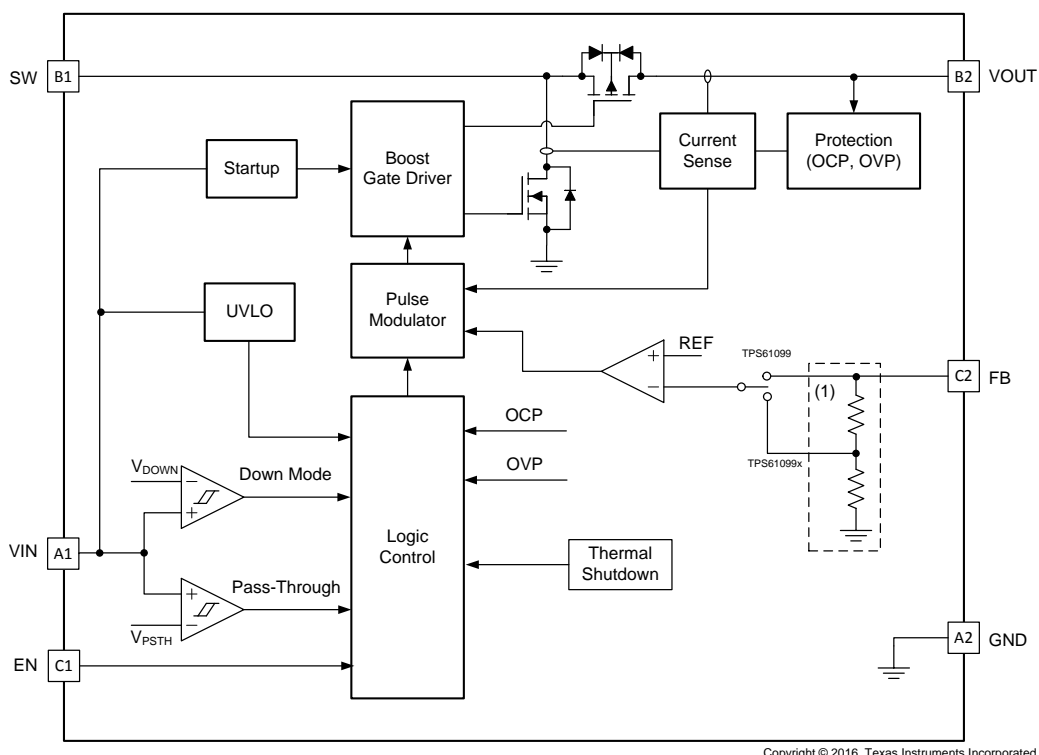
8 Detailed Description

8.1 Overview

The TPS61099x synchronous step-up converter is designed for alkaline battery, coin-cell battery, Li-ion or Li-polymer battery powered systems, which requires long battery running time and tiny solution size. The TPS61099x can operate with a wide input voltage from 0.7 V to 5.5 V. It only consumes 1 μ A quiescent current and can achieve high efficiency under light load condition.

The TPS61099x operates in a hysteretic control scheme with typical 1-A peak switch current limit. The TPS61099x provides the true shutdown function and the load is completely disconnected from the input so as to minimize the leakage current. It also adopts Down Mode and Pass-Through operation when input voltage is close to or higher than the regulated output voltage. The TPS61099x family is available in both adjustable and fixed output voltage versions. Adjustable version offers programmable output voltage for flexible applications while fixed versions offer minimal solution size and achieve up to 75% high efficiency under 10- μ A load.

8.2 Functional Block Diagrams



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(1) Internal FB resistor divider is implemented in fixed output voltage versions.

图 9. Functional Block Diagram

8.3 Feature Description

8.3.1 Boost Controller Operation

The TPS61099x boost converter is controlled by a hysteretic current mode controller. This controller regulates the output voltage by keeping the inductor ripple current constant in the range of 300 mA and adjusting the offset of this inductor current depending on the output load. Since the input voltage, output voltage and inductor value all affect the rising and falling slopes of inductor ripple current, the switching frequency is not fixed and is determined by the operation condition. If the required average input current is lower than the average inductor current defined by this constant ripple, the inductor current goes discontinuously to keep the efficiency high under light load condition. [图 10](#) illustrates the hysteretic current operation. If the load current is reduced further, the

Feature Description (接下页)

boost converter enters into Burst mode. In Burst mode, the boost converter ramps up the output voltage with several switching cycles. Once the output voltage exceeds a setting threshold, the device stops switching and goes into a sleep status. In sleep status, the device consumes less quiescent current. It resumes switching when the output voltage is below the setting threshold. It exits the Burst mode when the output current can no longer be supported in this mode. Refer to 图 11 for Burst mode operation details.

To achieve high efficiency, the power stage is realized as a synchronous boost topology. The output voltage V_{OUT} is monitored via an external or internal feedback network which is connected to the voltage error amplifier. To regulate the output voltage, the voltage error amplifier compares this feedback voltage to the internal voltage reference and adjusts the required offset of the inductor current accordingly.

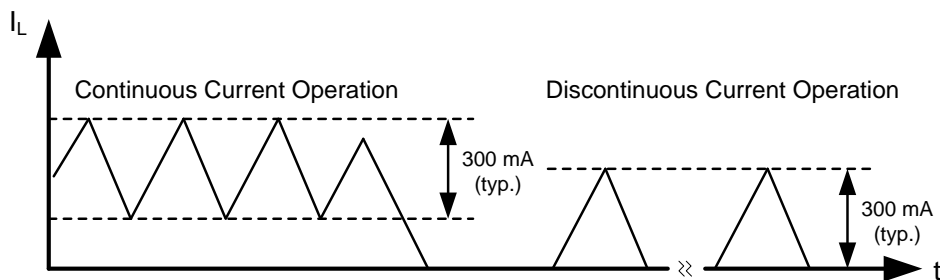


图 10. Hysteretic Current Operation

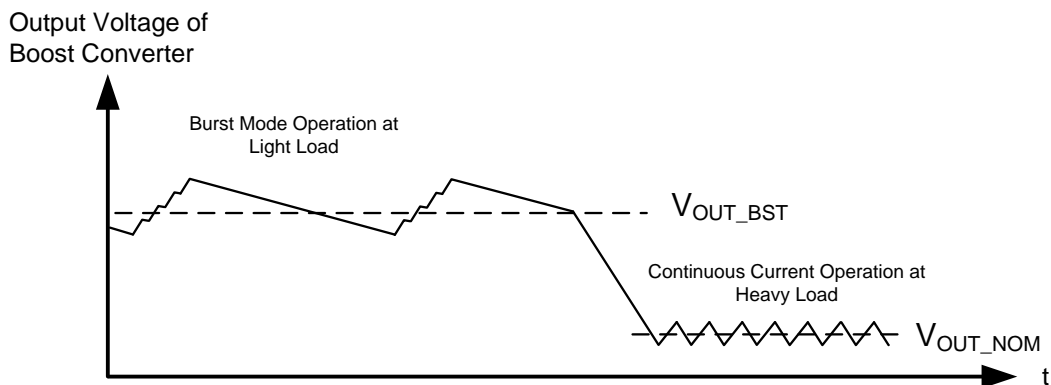


图 11. Burst Mode Operation

8.3.2 Under-Voltage Lockout

An under-voltage lockout (UVLO) circuit stops the operation of the converter when the input voltage drops below the typical UVLO threshold of 0.4 V. A hysteresis of 200 mV is added so that the device cannot be enabled again until the input voltage goes up to 0.6 V. This function is implemented in order to prevent malfunctioning of the device when the input voltage is between 0.4 V and 0.6 V.

8.3.3 Enable and Disable

When the input voltage is above UVLO rising threshold and the EN pin is pulled to high voltage, the TPS61099x is enabled. When the EN pin is pulled to low voltage, the TPS61099x goes into shutdown mode. In shutdown mode, the device stops switching and the rectifying PMOS fully turns off, providing the completed disconnection between input and output. Less than 0.5- μ A input current is consumed in shutdown mode.

Feature Description (接下页)

8.3.4 Soft Start

After the EN pin is tied to high voltage, the TPS61099x begins to startup. At the beginning, the device operates at the boundary of Discontinuous Conduction Mode (DCM) and Continuous Conduction Mode (CCM), and the inductor peak current is limited to around 200 mA during this stage. When the output voltage is charged above approximately 1.6 V, the device starts the hysteretic current mode operation. The current limit threshold is gradually increasing to $0.7 \times I_{LIM}$ within 500 μ s. In this way, the soft start function reduces the inrush current during startup. After V_{OUT} reaches the target value, soft start stage ends and the peak current is now determined by the output of an internal error amplifier which compares the feedback of the output voltage and the internal reference voltage.

The TPS61099x is able to start up with 0.7-V input voltage with larger than 3-k Ω load. However, if the load during startup is so heavy that the TPS61099x fails to charge the output voltage above 1.6 V, the TPS61099x can't start up successfully until the input voltage is increased or the load current is reduced. The startup time depends on input voltage and load current.

8.3.5 Current Limit Operation

The TPS61099x employs cycle-by-cycle over-current protection (OCP) function. If the inductor peak current reaches the current limit threshold I_{LIM} , the main switch turns off so as to stop further increase of the input current. In this case the output voltage will decrease until the power balance between input and output is achieved. If the output drops below the input voltage, the TPS61099x enters into Down Mode. The peak current is still limited by I_{LIM} cycle-by-cycle in Down Mode. If the output drops below 1.6 V, the TPS61099 enters into startup process again. In Pass-Through operation, current limit function is not enabled.

8.3.6 Output Short-to-Ground Protection

The TPS61099x starts to limit the switch current to 200 mA when the output voltage is below 1.6 V. If short-to-ground condition occurs, switch current is limited at 200 mA. Once the short circuit is released, the TPS61099x goes back to soft start again and regulates the output voltage.

8.3.7 Over Voltage Protection

TPS61099x has an output over-voltage protection (OVP) to protect the device in case that the external feedback resistor divider is wrongly populated. When the output voltage of the TPS61099 exceeds the OVP threshold of 5.8 V, the device stops switching. Once the output voltage falls 0.1 V below the OVP threshold, the device starts operating again.

8.3.8 Down Mode Regulation and Pass-Through Operation

The TPS61099x features Down Mode and Pass-Through operation when input voltage is close to or higher than output voltage.

In the Down Mode, output voltage is regulated at target value even when $V_{IN} > V_{OUT}$. The control circuit changes the behavior of the rectifying PMOS by pulling its gate to input voltage instead of to ground. In this way, the voltage drop across the PMOS is increasing as high as to regulate the output voltage. The power loss also increases in this mode, which needs to be taken into account for thermal consideration.

In the Pass-Through operation, the boost converter stops switching. The rectifying PMOS constantly turns on and low side switch constantly turns off. The output voltage is the input voltage minus the voltage drop across the dc resistance (DCR) of the inductor and the on-resistance of the rectifying PMOS.

With V_{IN} ramping up, the TPS61099x goes into Down Mode first when $V_{IN} > V_{OUT} - 50$ mV. It stays in Down Mode until $V_{IN} > V_{OUT} + 0.3$ V and then goes automatically into Pass-Through operation. In the Pass-Through operation, output voltage follows input voltage. The TPS61099x exits Pass-Through Mode and goes back to Down Mode when V_{IN} ramps down to 103% of the target output voltage. It stays in Down Mode until input voltage falls 100mV below the output voltage, returning to Boost operation.

Feature Description (接下页)

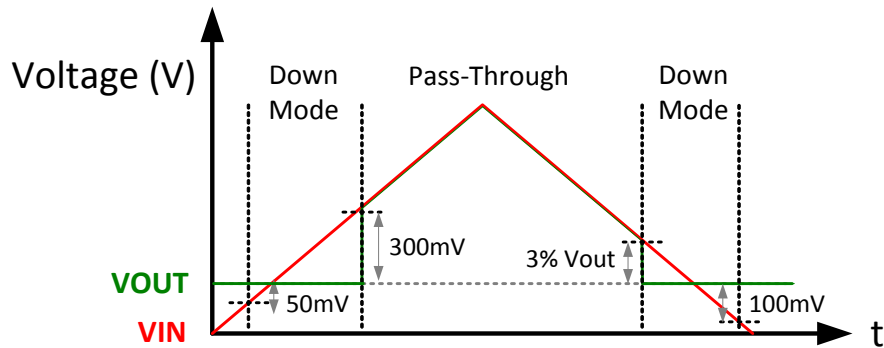


图 12. Down Mode and Pass-Through Operation

8.3.9 Thermal Shutdown

The TPS61099x has a built-in temperature sensor which monitors the internal junction temperature in boost mode operation. If the junction temperature exceeds the threshold 150°C, the device stops operating. As soon as the junction temperature drops below the shutdown temperature minus the hysteresis, typically 125°C, it starts operating again.

8.4 Device Functional Modes

8.4.1 Burst Mode Operation under Light Load Condition

The boost converter of TPS61099x enters into Burst Mode operation under light load condition. Refer to [Boost Controller Operation](#) for details.

8.4.2 Down Mode Regulation and Pass-Through Mode Operation

The boost converter of TPS61099x automatically enters into Down Mode or pass-through mode operation when input voltage is higher than the target output voltage. Refer to [Down Mode Regulation and Pass-Through Operation](#) for details.

9 Applications and Implementation

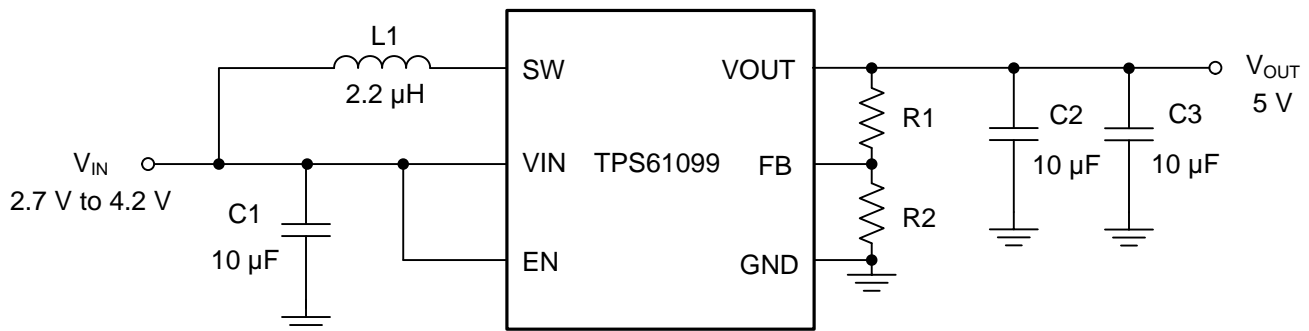
注

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

The TPS61099x is a synchronous boost converter designed to operate at a wide input voltage from 0.7 V to 5.5 V with 1-A peak switch current limit. The device adopts a hysteretic control scheme so the operating frequency is not a constant value, which varies with different input/output voltages and inductor values. It only consumes 1- μ A quiescent current under light load condition. It also supports true shutdown to disconnect the load from the input in order to minimize the leakage current. Therefore, it is very suitable for alkaline battery, coin-cell battery, Li-ion or Li-polymer battery powered systems to extend the battery running time.

9.2 Typical Application - 5 V Output Boost Converter



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9.2.1 Design Requirements

A typical application example is the memory LCD, which normally requires 5-V output as its bias voltage and only consumes less than 1 mA current. The following design procedure can be used to select external component values for the TPS61099x.

表 1. Design Requirements

PARAMETERS	VALUES
Input Voltage	2.7 V ~ 4.2 V
Output Voltage	5 V
Output Current	1 mA
Output Voltage Ripple	± 50 mV

9.2.1.1 Detailed Design Procedure

9.2.1.1.1 Programming the Output Voltage

There are two ways to set the output voltage of the TPS61099x. For adjustable output voltage version, select the external resistor divider R1 and R2, as shown in 公式 1, the output voltage is programmed to the desired value. When the output voltage is regulated, the typical voltage at the FB pin is V_{REF} of 1.0 V.

$$V_{OUT} = V_{REF} \cdot \frac{R1 + R2}{R2} \quad (1)$$

For fixed output voltage versions, the FB pin should be connected to the V_{OUT} pin directly. The TPS61099x offers diverse fixed voltage versions, refer to [Device Comparison Table](#) for version details.

In this example, 5-V output is required to bias the memory LCD. For the best accuracy, the current following through R2 should be 100 times larger than FB pin leakage current. Changing R2 towards a lower value increases the robustness against noise injection. Changing R2 towards higher values reduces the FB divider current for achieving the highest efficiency at low load currents. 1-M Ω and 249-k Ω resistors are selected for R1 and R2 in this example. High accuracy resistors are recommended for better output voltage accuracy.

9.2.1.1.2 Maximum Output Current

The maximum output capability of the TPS61099x is determined by the input to output ratio and the current limit of the boost converter. It can be estimated by [公式 2](#).

$$I_{OUT(max)} = \frac{V_{IN} \cdot (I_{LIM} - \frac{I_{LH}}{2}) \cdot \eta}{V_{OUT}}$$

where

- η is the conversion efficiency, use 85% for estimation
 - I_{LH} is the current ripple value
 - I_{LIM} is the switch current limit
- (2)

Minimum input voltage, maximum boost output voltage and minimum current limit I_{LIM} should be used as the worst case condition for the estimation.

9.2.1.1.3 Inductor Selection

Because the selection of the inductor affects steady state operation, transient behavior, and loop stability, the inductor is the most important component in power regulator design. There are three important inductor specifications, inductor value, saturation current, and dc resistance (DCR).

The TPS61099x is optimized to work with inductor values between 1 μ H and 2.2 μ H. For best stability consideration, a 2.2- μ H inductor is recommended under $V_{out} > 3.0V$ condition while choosing a 1- μ H inductor for applications under $V_{out} \leq 3.0V$ condition. Follow [公式 3](#) and [公式 4](#) to calculate the inductor's peak current for the application. Depending on different load conditions, the TPS61099x works in continuous current mode or discontinuous mode. In different modes, the peak currents of the inductor are also different. [公式 3](#) provides an easy way to estimate whether the device works in CCM or DCM. As long as the [公式 3](#) is true, continuous current mode is typically established. Otherwise, discontinuous current mode is typically established.

$$\frac{V_{OUT} \cdot I_{OUT}}{V_{IN} \times \eta} > \frac{I_{LH}}{2}$$
(3)

The inductor current ripple I_{LH} is fixed by design. Therefore, the peak inductor current is calculated with [公式 4](#).

$$I_{L,peak} = \frac{V_{OUT} \cdot I_{OUT}}{V_{IN} \times \eta} + \frac{I_{LH}}{2}; \text{ continuous current mode operation}$$

$$I_{L,peak} = I_{LH}; \text{ discontinuous current mode operation}$$

where

- $I_{L,peak}$ is the peak inductor current.
- (4)

The inductor's saturation current must be higher than the calculated peak inductor current. [表 2](#) lists the recommended inductors for TPS61099x device.

After choosing the inductor, the estimated switching frequency f in continuous current mode can be calculated by [公式 5](#). The switching frequency is not a constant value, which is determined by L, V_{IN} and V_{OUT} .

$$f = \frac{V_{IN} \cdot (V_{OUT} - V_{IN} \cdot \eta)}{L \cdot I_{LH} \cdot V_{OUT}}$$
(5)

表 2. List of Inductors⁽¹⁾

VOUT [V]	INDUCTANCE [μH]	SATURATION CURRENT [A]	DC RESISTANCE [mΩ]	SIZE (LxWxH)	PART NUMBER	MANUFACTURER
> 3.0	2.2	1.95	80	2.5 x 2.0 x 1.2	74404024022	Würth Elektronik
	2.2	1.7	92	2.5 x 2.0 x 1.1	LQH2HPN2R2MJR	muRata
	2.2	1.45	163	2.0 x 1.6 x 1.0	VLS201610CX-2R2M	TDK
≤ 3.0	1.0	2.6	37	2.5 x 2.0 x 1.2	74404024010	Würth Elektronik
	1.0	2.3	48	2.5 x 2.0 x 1.0	MLP2520W1R0MT0S1	TDK
	1.0	1.5	80	2.0 x 1.2 x 1.0	LQM21PN1R0MGH	muRata

(1) See [Third-Party Products](#) disclaimer

9.2.1.1.4 Capacitor Selection

For best output and input voltage filtering, low ESR X5R or X7R ceramic capacitors are recommended.

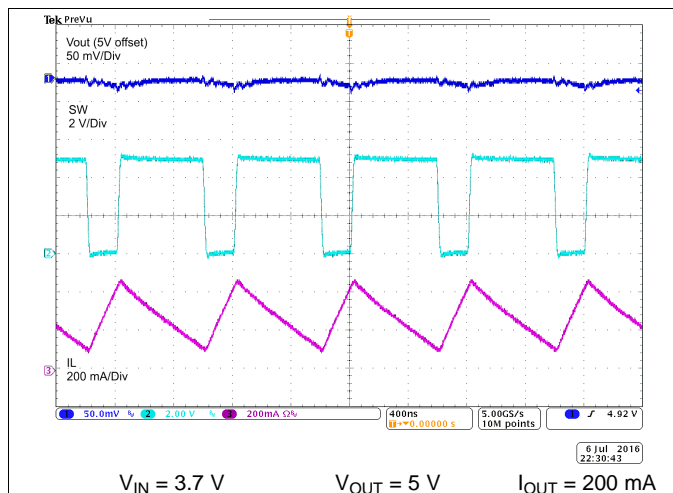
The input capacitor minimizes input voltage ripple, suppresses input voltage spikes and provides a stable system rail for the device. An input capacitor value of 10 μF is normally recommended to improve transient behavior of the regulator and EMI behavior of the total power supply circuit. A ceramic capacitor placed as close as possible to the VIN and GND pins of the IC is recommended.

For the output capacitor of VOUT pin, small ceramic capacitors are recommended, placed as close as possible to the VOUT and GND pins of the IC. If, for any reason, the application requires the use of large capacitors which cannot be placed close to the IC, the use of a small ceramic capacitor with a capacitance value of 1 μF in parallel to the large one is recommended. This small capacitor should be placed as close as possible to the VOUT and GND pins of the IC.

From the power stage point of view, the output capacitor sets the corner frequency of the converter while the inductor creates a Right-Half-Plane-Zero. Consequently, with a larger inductor, a larger output capacitor must be used. The TPS61099x is optimized to work with the inductor from 1 μH to 2.2 μH, so the minimal output capacitor value is 20 μF (nominal value). Increasing the output capacitor makes the output ripple smaller in PWM mode.

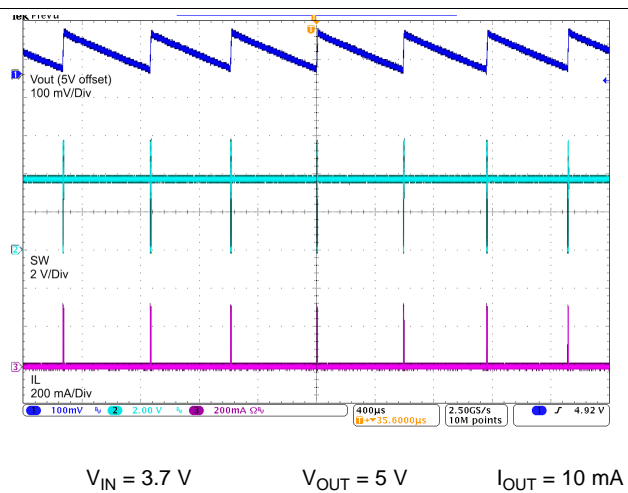
When selecting capacitors, ceramic capacitor's derating effect under bias should be considered. Choose the right nominal capacitance by checking capacitor's DC bias characteristics. In this example, GRM188R60J106ME84D, which is a 10-μF ceramic capacitor with high effective capacitance value at DC biased condition, is selected for V_{OUT} rail. The performance of TPS61099x is shown in [Application Curves](#) section.

9.2.1.2 Application Curves



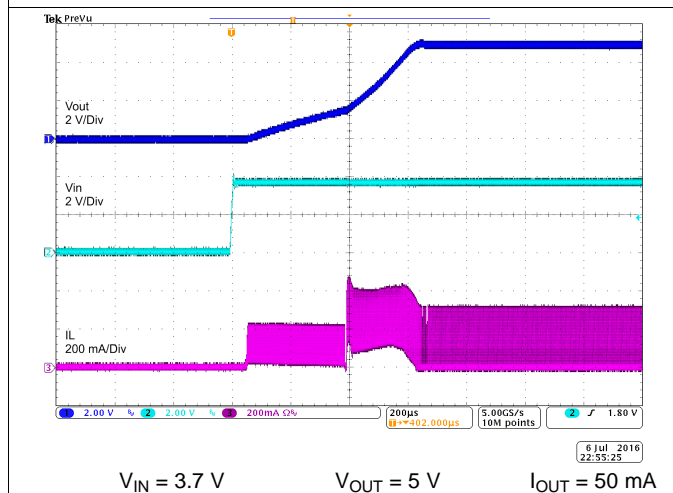
$V_{IN} = 3.7\text{ V}$ $V_{OUT} = 5\text{ V}$ $I_{OUT} = 200\text{ mA}$

图 13. Switching Waveform at Heavy Load



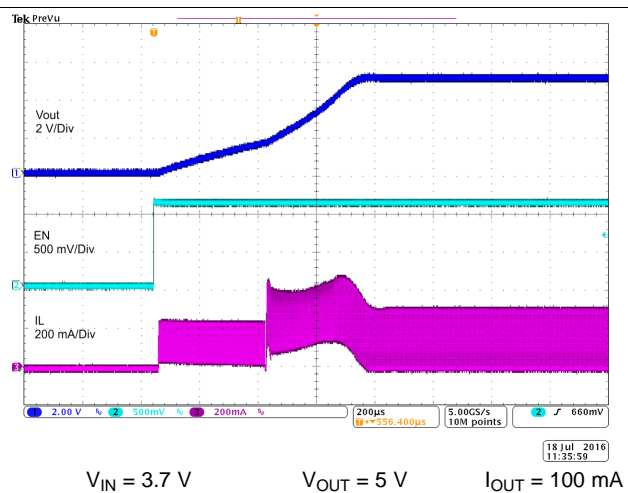
$V_{IN} = 3.7\text{ V}$ $V_{OUT} = 5\text{ V}$ $I_{OUT} = 10\text{ mA}$

图 14. Switching Waveform at Light Load



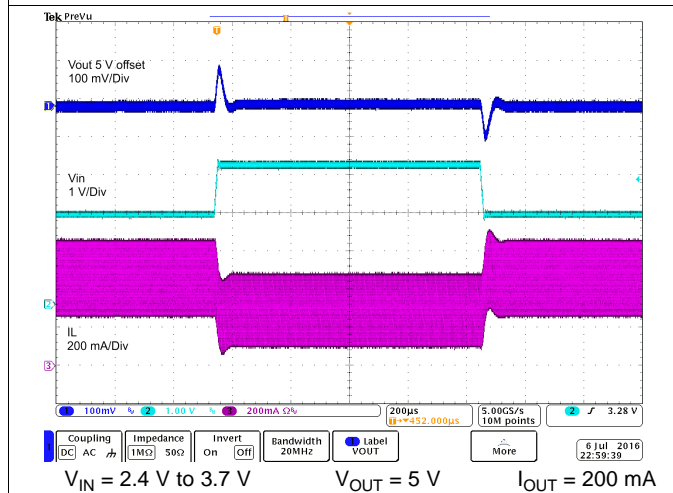
$V_{IN} = 3.7\text{ V}$ $V_{OUT} = 5\text{ V}$ $I_{OUT} = 50\text{ mA}$

图 15. Startup by VIN



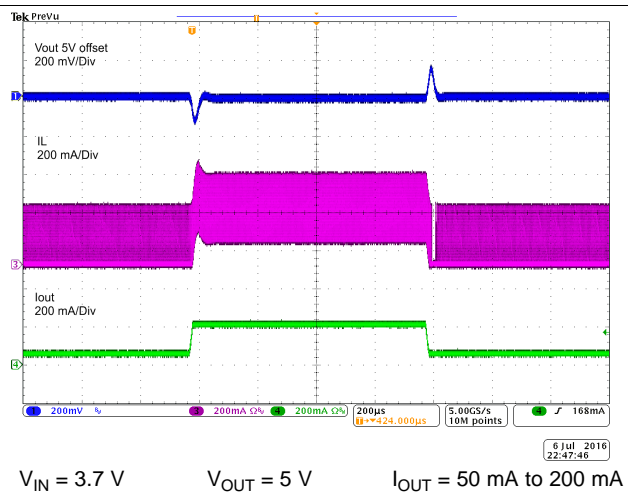
$V_{IN} = 3.7\text{ V}$ $V_{OUT} = 5\text{ V}$ $I_{OUT} = 100\text{ mA}$

图 16. Startup by EN



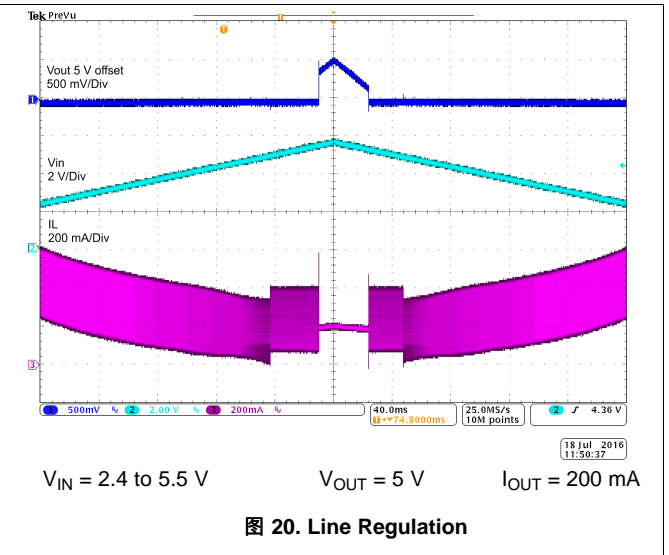
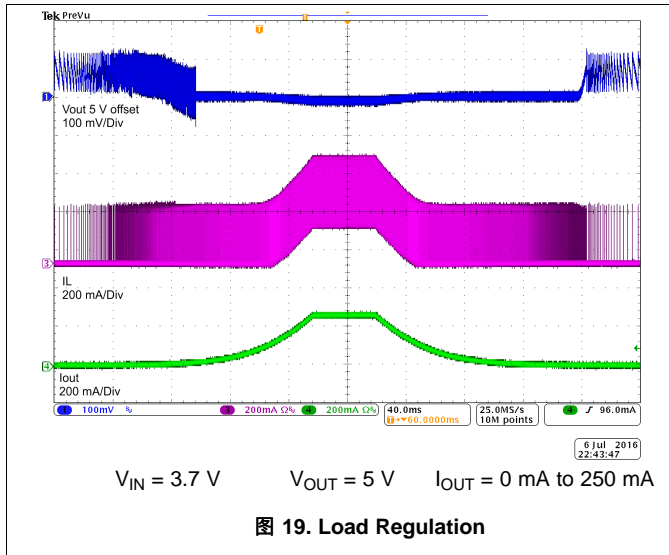
$V_{IN} = 2.4\text{ V to } 3.7\text{ V}$ $V_{OUT} = 5\text{ V}$ $I_{OUT} = 200\text{ mA}$

图 17. Line Transient



$V_{IN} = 3.7\text{ V}$ $V_{OUT} = 5\text{ V}$ $I_{OUT} = 50\text{ mA to } 200\text{ mA}$

图 18. Load Transient



10 Power Supply Recommendations

The TPS61099x family is designed to operate from an input voltage supply range between 0.7 V to 5.5 V. The power supply can be alkaline battery, NiMH rechargeable battery, Li-Mn battery or rechargeable Li-Ion battery. The input supply should be well regulated with the rating of TPS61099x.

11 Layout

11.1 Layout Guidelines

As for all switching power supplies, the layout is an important step in the design, especially at high peak currents and high switching frequencies. If the layout is not carefully done, the regulator could show stability problems as well as EMI problems. Therefore, use wide and short traces for the main current path and for the power ground paths. The input and output capacitor, as well as the inductor should be placed as close as possible to the IC.

11.2 Layout Example

The bottom layer is a large GND plane connected by vias.

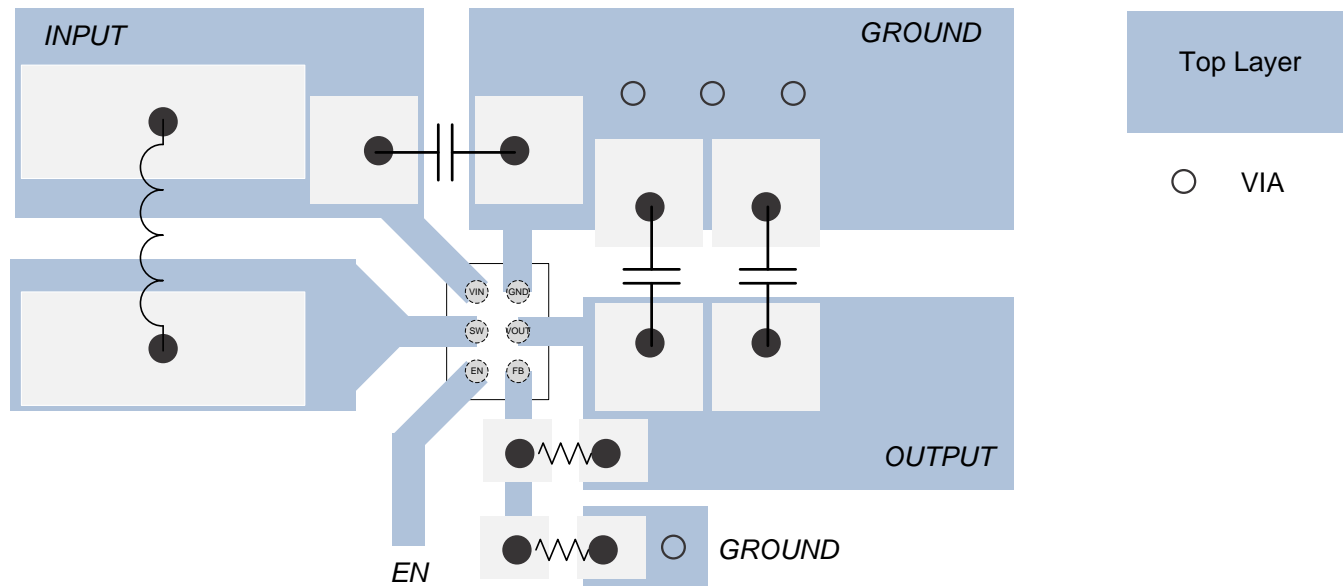


图 21. Layout

12 器件和文档支持

12.1 器件支持

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12.2 文档支持

12.2.1 相关文档

相关文档请参见以下部分：

- 《执行精确的 PFM 模式效率测量》，[SLVA236](#)
- 《精确测量超低 IQ 器件的效率》，[SLYT558](#)
- 《IQ：它是什么、不是什么以及如何使用》，[SLYT412](#)

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12.7 Glossary

[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

13 机械、封装和可订购信息

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Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TPS610993YFFR	PREVIEW	DSBGA	YFF	6	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	17X	
TPS610993YFFT	PREVIEW	DSBGA	YFF	6	250	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	17X	
TPS610994YFFR	ACTIVE	DSBGA	YFF	6	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	17N	Samples
TPS610994YFFT	ACTIVE	DSBGA	YFF	6	250	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	17N	Samples
TPS610997YFFR	ACTIVE	DSBGA	YFF	6	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	14K	Samples
TPS610997YFFT	ACTIVE	DSBGA	YFF	6	250	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	14K	Samples
TPS61099YFFR	ACTIVE	DSBGA	YFF	6	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	12G	Samples
TPS61099YFFT	ACTIVE	DSBGA	YFF	6	250	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	12G	Samples

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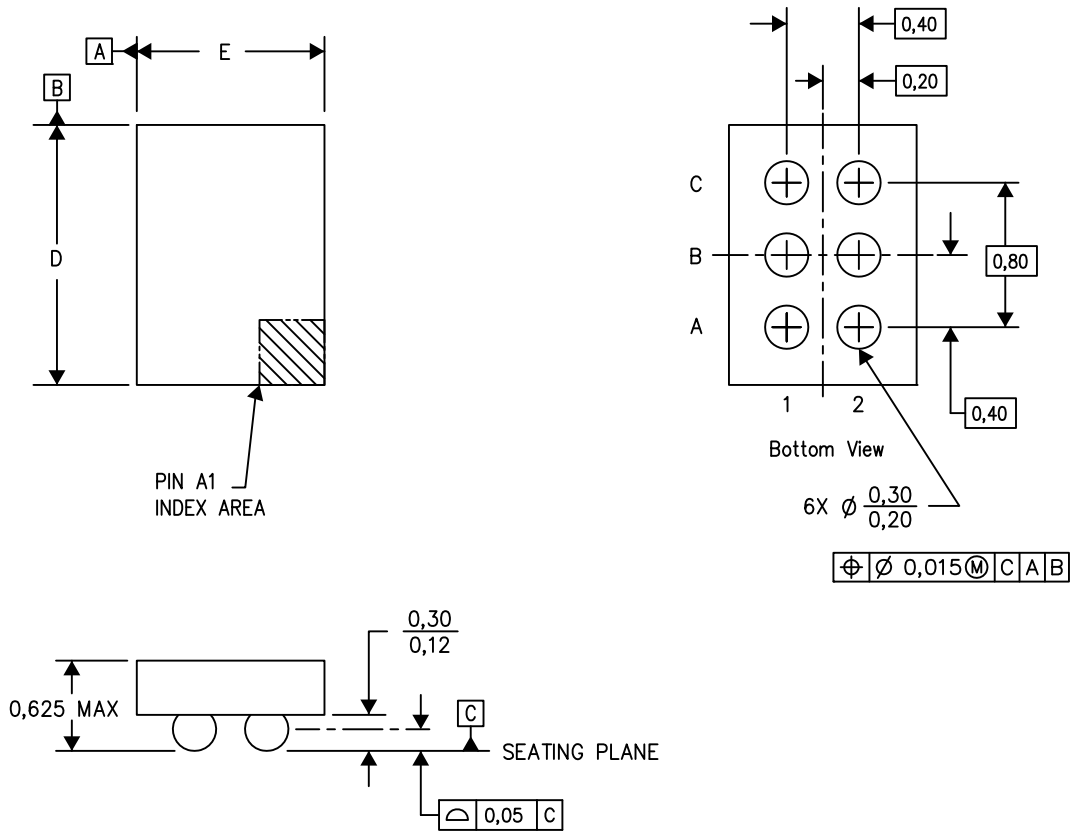
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MECHANICAL DATA

YFF (R-XBGA-N6)

DIE-SIZE BALL GRID ARRAY



D: Max = 1.256 mm, Min = 1.196 mm

E: Max = 0.914 mm, Min = 0.854 mm

4207625-4/A0 12/13

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